

Page 1 (U.S. Patents)

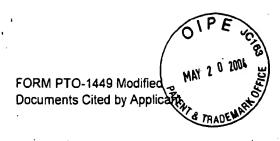
U.S. App. No.: 09/853,925 Filed: May 9, 2001 Group: 2813

Applicant: Chu et al Docket No.: NSWC-1008US

Examiner	Item				_	
Initial	No.	Document No.	Date	Name	Class	Subclass
EX	1US	3,642,526	Feb-72	Itoh, et al.		
ì	2US	3,784,402	Jan-74	Reedy, Jr.		
	3US	4,368,098	Jan-83	Manasevit		
	4US	4,765,845	Aug-88	Takada, et al.		
	5US	4,983,535	Jan-91	Blanchard		
	6US	4,996,584	Feb-91	Young, et al.		
	7US	5,036,017	Jul-91	Noda		•
	8US	5,084,417	Jan-92	Joshi, et al.	•	
	9US	5,135,808	Aug-92	Kimock, et al.		
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	12US	5,232,872	Aug-93	Ohba		
	13US	5,280,012	Jan-94	Kirlin et al.		
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	15US	5,400,739	Mar-95	Kao et al.		
	16US	5,453,494		Kirlin et al.		
	17US	5,625,204	Apr-97	Kao et al.		
	18US	5,920,080	Jul-99	Jones		
	19US	5,932,006	Aug-99	Santiago et al.		
	20US	5,955,785	Sep-99	Gardner et al.		
	21US	5,965,810	Oct-99	Holbrook		
	22US	5,968,847	Oct-99	Ye et al.		
	23US	6,077,775	Jun-00	Stumborg et al.		
	24US	6,120,844	Sep-00	Chen et al.	•	
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Page 1 (Foreign)

U.S. App. No.: 09/853,925 Filed: May 9, 2001 Group: 2813

Applicant: Chu et al Docket No.: NSWC-1008US

Examiner Initial	Item No.	Foreign Patent Document No.	Date	Country	Translation (Yes/No)
C/L.	1F	WO 00/11731	3/1/2000	PCT	\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\\
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_ {K	3F	JP 6-164004	6/10/1994	Japan	
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Page 1 (Other Documents)

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List of Patents and Problications and by Applicant
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U.S. App. No.: 09/853,925 Filed: May 9, 2001

Group: 2813

Applicant: Chu et al Docket No.: NSWC-1008US

	<u></u>	14	Docket No.: NSWC-10000				
	Examin r	Item	Other Design and Design Author Title Date Leasting and Design and Design				
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	· 6		Vogt et al., "Dielectric Barriers for Cu Metallization Systems", Materials for Advanced				
	Ce	10D	Metallization, MAM '97, pp 51-52, 1998				
	_		"Electrically reprogrammable FAMOS structure," IBM Technical Disclosure Bulletin,				
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